
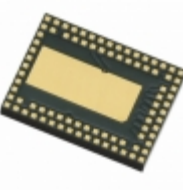
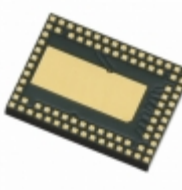

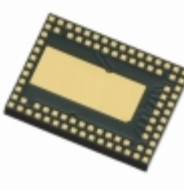

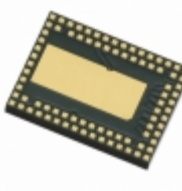

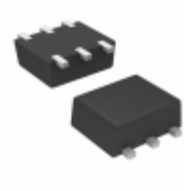
	<h2>SI1035X-T1-GE3</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI1035X-T1-GE3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Electro-Films (EFI) / Vishay</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N/P-CH 20V SC-89</p> <p><b>Datenblätter:</b>  <a href="#">SI1035X-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 18985 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">SI1035X-T1-GE3</a>
Hersteller	<a href="#">Electro-Films (EFI) / Vishay</a>
Beschreibung	MOSFET N/P-CH 20V SC-89
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	18985 pcs Stock
Hersteller Standard Vorlaufzeit	33 Weeks
detaillierte Beschreibung	Mosfet Array N and P-Channel 20V 180mA, 145mA
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	250mW
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SC-89-6
Typ FET	N and P-Channel
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	180mA, 145mA
Rds On (Max) @ Id, Vgs	5 Ohm @ 200mA, 4.5V
VGS (th) (Max) @ Id	400mV @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	0.75nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)
Basisteilenummer	SI1035
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI1035X-T1-GE3TR



















































SI1035X-T1-GE3 ist neu im Original, Suche SI1035X-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1035X-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI1035X-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI1036-B-GM3</b> Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM&lt;1GHZ 85-VFLGA</p>	 <p><b>SI1035-B-GM3</b> Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM&lt;1GHZ 85-VFLGA</p>	 <p><b>SI1035X-T1-GE3</b> Vishay / Siliconix MOSFET N/P-CH 20V SC-89</p>	 <p><b>SI1035-B-GM3R</b> Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM&lt;1GHZ 85-VFLGA</p>
 <p><b>SI1036-A-GMR</b> Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM&lt;1GHZ 85-VFLGA</p>	 <p><b>SI1036-B-GM3R</b> Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM&lt;1GHZ 85-VFLGA</p>	 <p><b>SI1036-A-GM</b> Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM&lt;1GHZ 85-VFLGA</p>	 <p><b>SI1035X-T1-E3</b> Vishay / Siliconix MOSFET N/P-CH 20V SOT563F</p>

heiße Teile

Mehr

Contact us:[Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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